

Synthesis of Substituted Aminogallanes by Alkyltrimethyltin Elimination

W. Rodger Nutt,^{*,1a} Kelly J. Murray,^{1a} James M. Gulick,^{1b} Jerome D. Odom,^{1b}
Yan Ding,^{1b} and Lukasz Lebioda^{1b}

Departments of Chemistry, Martin Chemical Laboratory, Davidson College,
Davidson, North Carolina 28036, and University of South Carolina,
Columbia, South Carolina 29208

Received October 13, 1995[®]

Alkyltrimethyltin elimination reactions of R_3Ga ($R = Me, Et$) with $R''R'NSnMe_3$ ($R'' = i-Bu, SnMe_3, C_6H_{11}$ and $R' = i-Bu, i-Pr, C_6H_{11}$) have been investigated. The aminogallanes $[Me_2GaN(i-Bu)_2]_2$, $[Et_2GaN(i-Bu)_2]_2$, $[Me_2GaN(i-Pr)SnMe_3]_2$, $[Me_2GaN(C_6H_{11})_2]_2$, and $[Et_2GaN(C_6H_{11})_2]_2$ were isolated in 88.6, 68.6, 69.1, 81.0, and 80.4% yields, respectively. X-ray crystallographic studies of $[Et_2GaN(i-Bu)_2]_2$, $[Me_2GaN(i-Pr)SnMe_3]_2$, $[Me_2GaN(C_6H_{11})_2]_2$, and $[Et_2GaN(C_6H_{11})_2]_2$ indicate that the four aminogallanes are dimeric in the solid state. The four-membered $(Ga-N)_2$ rings in $[Et_2GaN(i-Bu)_2]_2$ and $[Et_2GaN(C_6H_{11})_2]_2$ (molecules 1 and 2) are nonplanar with fold angles on the $Ga\cdots Ga$ diagonals of 148.7(3) and 146.3(3), 147.7(3)°. All five aminogallanes exist as dimers in benzene solutions. The 1H and ^{13}C NMR spectra are reported and discussed.

Introduction

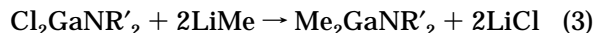
Traditionally, the alkane elimination (eq 1) reaction has been utilized to prepare the substituted aminogallanes $R_2GaNR'R''$ (R and $R'' = \text{alkyl or aryl}$ and $R' = H, \text{alkyl, or aryl}$). Elimination reactions between Me_3-



Ga and 10 different primary amines have been reported.^{2a–f} Typically, toluene solutions of the reactants, the reactants in sealed tubes, or the Lewis acid–base adducts of the reactants were heated at temperatures from 100 to 160 °C for periods of 7–24 h and the resulting aminogallanes were isolated in yields that varied from 67 to 100%. Reactions of Me_3Ga with secondary^{2f,g} or heterocyclic^{2h} amines also have been found to proceed under similar reaction conditions with comparable yields. Examples of elimination reactions that have involved trialkylgallium compounds other than Me_3Ga include those of Et_3Ga with ethyleneimine,^{2g} $(PhMe_2CCH_2)_3Ga$ with H_2NPr ,²ⁱ Et_3Ga or $(i-Bu)_3Ga$ with piperidine,^{2j} Bu_3Ga with $HNEt_2$,^{2k} $(c-C_3H_5)_3Ga$ with ethyleneimine,^{2l} and $(i-Pr)_3Ga \cdot OEt_2$ with $HN(i-Pr)_2$.^{2m} The first three reactions required temperatures of 120 °C or above for a period of several days or until gas

evolution had ceased. The product $[(PhMe_2CCH_2)_2GaN(H)Pr]_2$ was obtained in 83% yield. In the case of the $Bu_3Ga/HNEt_2$ reaction, the reactants were heated to boiling for 1.5 h. Interestingly, the reactions of $(c-C_3H_5)_3Ga$ with ethyleneimine and $(i-Pr)_3Ga \cdot OEt_2$ with $HN(i-Pr)_2$ in benzene proceeded at or below room temperature and the aminogallanes were isolated in 85 and 90% yields. Also, $Me_2Ga\{2-[N(CH_2C_6H_5)]NC_5H_4\}-(OEt_2)$ was obtained in 73% yield from the reaction of Me_3Ga (prepared *in situ*) with 2-(benzylamino)pyridine in diethyl ether at room temperature.²ⁿ The alkane elimination reaction offers a simple, single-step synthetic route to aminogallanes. Generally, this synthetic procedure does not require a solvent and the yields are high. However, in most cases temperatures above 100 °C are needed to effect the formation of the aminogallane.

A number of monomeric^{3ab} and dimeric^{3c–g} aminogallanes have been prepared by LiCl elimination (eqs 2 and 3). In these examples hexane, diethyl ether, or hexane/



diethyl ether solutions of the reactants were mixed at or below 0 °C and the resulting mixtures were stirred at room temperature or heated for a period of 4–18 h. The yields varied from 52 to 86%. This synthetic method offers the advantage of a facile, low-temperature pathway to the preparation of aminogallanes with bulky

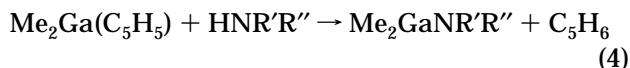
[®] Abstract published in *Advance ACS Abstracts*, February 15, 1996.
(1) (a) Davidson College. (b) University of South Carolina.

(2) (a) Waggoner, K. M.; Power, P. P. *J. Am. Chem. Soc.* **1991**, *113*, 3393. (b) Byers, J. J.; Lee, B.; Pennington, W. T.; Robinson, G. H. *Polyhedron* **1992**, *11*, 967. (c) Lee, B.; Pennington, W. T.; Robinson, G. H. *Inorg. Chim. Acta* **1991**, *190*, 173. (d) Park, J. T.; Kim, Y.; Kim, J.; Kim, Y. *Organometallics* **1992**, *11*, 3320. (e) Ferry, J. M.; Cole-Hamilton, D. J.; Mullin, J. B. *Chemtronics* **1989**, *4*, 141. (f) Coates, G. E. *J. Chem. Soc.* **1951**, 2003. (g) Storr, A.; Thomas, B. S. *J. Chem. Soc. (A)* **1971**, 3850. (h) Beachley, O. T., Jr.; Bueno, C.; Churchill, M. R.; Hallock, R. B.; Simmons, R. G. *Inorg. Chem.* **1981**, *20*, 2423. (i) Beachley, O. T., Jr.; Noble, M. J.; Churchill, M. R.; Lake, C. H. *Organometallics* **1992**, *11*, 1051. (j) Sen, B.; White, L. J. *Inorg. Nucl. Chem.* **1973**, *35*, 2207. (k) Haran, R.; Jouany, C.; Laurent, J. P. *Bull. Soc. Chem. Fr.* **1968**, 457. (l) Müller, J.; Margiolis, K.; Dehnicke, K. *J. Organomet. Chem.* **1972**, *46*, 219. (m) Hoffmann, G. G.; Fischer, R. Z. *Anorg. Allg. Chem.* **1990**, *590*, 181. (n) Zhou, Y.; Richeson, D. S. *Organometallics* **1995**, *14*, 3558.

(3) (a) Waggoner, K. M.; Ruhlandt-Senge, K.; Wehmschulte, R. J.; He, X.; Olmstead, M. M.; Power, P. P. *Inorg. Chem.* **1993**, *32*, 2557. (b) Brothers, P. J.; Wehmschulte, R. J.; Olmstead, M. M.; Ruhlandt-Senge, K.; Parkin, S. R.; Power, P. P. *Organometallics* **1994**, *13*, 2792. (c) Bradley, D. C.; Dawes, H. M.; Hursthouse, M. B.; Smith, L. M.; Thornton-Pett, M. *Polyhedron* **1990**, *9*, 343. (d) Atwood, D. A.; Jones, R. A.; Cowley, A. H.; Bott, S. G.; Atwood, J. L. *J. Organomet. Chem.* **1992**, *434*, 143. (e) Atwood, D. A.; Jones, R. A.; Cowley, A. H.; Bott, S. G.; Atwood, J. L. *Polyhedron* **1991**, *10*, 1897. (f) Atwood, D. A.; Atwood, V. O.; Carriker, D. E.; Cowley, A. H.; Gabbai, F. P.; Jones, R. A.; Bond, M. R.; Carrano, C. J. *J. Organomet. Chem.* **1993**, *463*, 29. (g) Herberich, G. E.; Englert, U.; Posselt, D. *J. Organomet. Chem.* **1993**, *461*, 21.

substituents on both the gallium and nitrogen atoms. The monomeric aminogallanes (*t*-Bu)₂GaN(1-Ad)SiPh₃ and Trip₂GaNPh₂ (1-Ad = 1-adamantyl; Trip = 2,4,6-triisopropylphenyl) were isolated in 67 and 62% yields.^{3a} However, the procedure requires several steps, the yields are usually lower than the yields in alkane elimination reactions, and solvents are needed.

Recently, Me₂Ga(C₅H₅) has been found to undergo a cyclopentadiene elimination reaction (eq 4) with several primary and secondary amines.⁴ These elimination



reactions occurred overnight at or below room temperature in benzene or pentane solutions, and the resulting aminogallanes were obtained in yields of 63–90%. Like the alkane elimination reaction, the cyclopentadiene elimination reaction provides a simple, single-step synthetic route to aminogallanes. Unlike the alkane elimination reaction, however, reaction temperatures above 100 °C are not required. However, the elimination of cyclopentadiene appears to be inhibited when the amine has bulky substituents. No reaction was observed between Me₂Ga(C₅H₅) and dicyclohexylamine, 2,4,6-tri-*tert*-butylaniline, or 2,2,4,4-tetramethylpiperidine.

As an extension of our studies of metathetical reactions between substituted gallanes and substituted aminosilanes,⁵ the alkyltrimethyltin elimination reactions of Me₃Ga or Et₃Ga with R'R'NSnMe₃ were investigated. Exothermic reactions of (*n*-Bu)₃B, Ph₃B, or Et₃Al with Me₂NSnMe₃ in diethyl ether, light petroleum ether, or benzene solvents have been reported, and the products (*n*-Bu)₂BNMe₂, Ph₂BNMe₂, and (Et₂AlNMe₂)₂ were isolated in 86, 59, and 50% yields.⁶ In addition, *t*-Bu(H)NSi(Me₂)N(*t*-Bu)GaMe₂ was prepared in 94% yield by allowing GaMe₃ to react with *t*-Bu(H)NSi(Me₂)N(*t*-Bu)SnMe₃ in benzene at 40 °C.⁷ These results suggest that the alkyltrimethyltin elimination reaction may afford a simple, single-step, low-temperature pathway to substituted aminogallanes.

Experimental Section

Materials and General Procedures. Trimethylgallium, triethylgallium, and trimethyltin chloride were purchased from Strem Chemicals and used without further purification. Diisobutylamine, isopropylamine, and dicyclohexylamine (Aldrich Chemical Co.) were distilled from calcium hydride prior to use. The compounds (*i*-Bu)₂NSnMe₃, *i*-PrN(SnMe₃)₂, and (C₆H₁₁)₂NSnMe₃ were prepared by published procedures.⁸ *Note:* trimethyltin compounds are toxic.⁹ The solvents diethyl ether, benzene, and pentane were refluxed over sodium/

benzophenone, calcium hydride, and sodium, respectively, and distilled into storage flasks. Toluene-*d*₈ (Aldrich Chemical Co.) was refluxed over calcium hydride and distilled into a storage flask. All experiments were performed under an oxygen-free, dry nitrogen or argon atmosphere by using Schlenk and glovebox techniques.¹⁰

The ¹H and ¹³C NMR spectra were obtained from toluene-*d*₈ solutions with a Bruker AC-300 or AM-500 spectrometer. The ¹H and ¹³C chemical shifts are reported in parts per million (ppm) with respect to Me₄Si at 0.0 ppm. The ¹H chemical shifts were referenced to the ¹H resonance of the residual CHD₂C₆D₅ (δ 2.09) solvent impurity, and the chemical shifts in the ¹³C spectra were referenced to the methyl ¹³C resonance of toluene-*d*₈ (δ 20.4). The molecular weights were determined cryoscopically in benzene with an apparatus similar to that described by Dilts and Shriver.¹¹ Melting points were obtained in sealed tubes on an Electrothermal IA 6304 melting point apparatus and are uncorrected. All elemental analyses were performed by E + R Microanalytical Laboratory, Corona, NY.

Reactions of Me₃Ga or Et₃Ga with R'R'NSnMe₃. R'R'NSnMe₃ was syringed into a 25 mL ampule that was equipped with a Teflon valve. The Me₃Ga or Et₃Ga was trap-to-trap distilled onto the aminostannane, and the ampule was allowed to stand at room temperature or was heated. Subsequently the volatile components were trap-to-trap distilled from the reaction solution or mixture and a solid remained. The composition of the distillate (Me₄Sn or EtSnMe₃ and unreacted trialkylgallium) was characterized by ¹H NMR.

[Me₂GaN(*i*-Bu)₂]₂. A solution of Me₃Ga (1.40 g, 12.2 mmol) and (*i*-Bu)₂NSnMe₃ (1.91 g, 6.53 mmol) was heated at 55–56 °C for 6 h. Recrystallization of the solid from pentane gave [Me₂GaN(*i*-Bu)₂]₂ (1.32 g, 88.6% yield): mp 72–74 °C; ¹H NMR (500.138 MHz) δ 2.78 (d, NCH₂, 4.0H), 1.95 (m, NCH₂CH(CH₃)₂, 2.0H), 0.86 (d, NCH₂CH(CH₃)₂, 12.0H), –0.02 (s, (CH₃)₂Ga, 5.5H); ¹³C NMR (125.759 MHz) δ 58.1 (NCH₂), 27.1 (NCH₂CH(CH₃)₂), 22.5 (NCH₂CH(CH₃)₂), –4.8 ((CH₃)₂Ga). Anal. Calcd for C₂₀H₄₈Ga₂N₂: C, 52.67; H, 10.61; N, 6.14. Found: C, 52.89; H, 10.81; N, 6.21. Molecular weight for C₂₀H₄₈Ga₂N₂: calcd, 456; found, 4.5 × 10² (calculated molality 0.0346).

[Et₂GaN(*i*-Bu)₂]₂. A solution of Et₃Ga (1.81 g, 11.5 mmol) and (*i*-Bu)₂NSnMe₃ (1.74 g, 5.96 mmol) was heated at 56–57 °C for 6 h. Recrystallization of the solid from pentane gave [Et₂GaN(*i*-Bu)₂]₂ (1.05 g, 68.6% yield): mp 97–98 °C; ¹H NMR (500.138 MHz) δ 2.87 (d, NCH₂, 4.1H), 1.96 (m, NCH₂CH(CH₃)₂, 2.0H), 1.37 (t, (CH₃CH₂)₂Ga, 6.1H), 0.91 (d, NCH₂CH(CH₃)₂, 12.0H), 0.74 (q, (CH₃CH₂)₂Ga, 4.2H); ¹³C NMR (125.759 MHz) δ 58.4 (NCH₂), 27.5 ((NCH₂CH(CH₃)₂), 22.7 (NCH₂CH(CH₃)₂), 11.2 ((CH₃CH₂)₂Ga), 5.0 ((CH₃CH₂)₂Ga). Anal. Calcd for C₂₄H₅₆Ga₂N₂: C, 56.28; H, 11.02; N, 5.47. Found: C, 56.27; H, 10.89; N, 5.47. Molecular weight for C₂₄H₅₆Ga₂N₂: calcd, 512; found, 5.3 × 10² (calculated molality 0.0311).

[Me₂GaN(*i*-Pr)SnMe₃]₂. A solution of Me₃Ga (1.38 g, 12.0 mmol) and *i*-PrN(SnMe₃)₂ (2.04 g, 5.31 mmol) was heated at 44–45 °C for 15.5 h. Recrystallization of the solid from pentane (2.0 mL)/diethyl ether (1.5 mL) gave [Me₂GaN(*i*-Pr)SnMe₃]₂ (1.18 g, 69.1% yield): mp 151–152 °C; ¹H NMR (300.133 MHz) δ 3.78 (sept, NCH, 1.1H), 1.02 (d, NCH(CH₃)₂, 6.8H), 0.38 (s, (CH₃)₃Sn, 8.7H, ²J_{Sn-H} = 52.7 Hz), –0.09 (s, (CH₃)₂Ga, 6.0H); ¹³C NMR (75.469 MHz) δ 53.6 (NCH, ²J_{Sn-C} = 19.5 Hz), 29.3 (NCH(CH₃)₂, ³J_{Sn-C} = 14.8 Hz), 2.4 ((CH₃)₃Sn, ¹J_{Sn-C} = 365, 349 Hz), –0.8 ((CH₃)₂Ga). Anal. Calcd for C₁₆H₄₄Ga₂N₂Sn₂: C, 29.96; H, 6.92; N, 4.37. Found: C, 30.13; H, 7.11; N, 4.44. Molecular weight for C₁₆H₄₄Ga₂N₂Sn₂: calcd, 641; found, 6.3 × 10² (calculated molality 0.0296).

[Me₂GaN(C₆H₁₁)₂]₂. After the ampule had been warmed to room temperature, the solution of Me₃Ga (0.425 g, 3.70 mmol) and (C₆H₁₁)₂NSnMe₃ (0.936 g, 2.72 mmol) slowly

(4) Beachley, O. T., Jr.; Royster, T. L.; Arhar, J. R.; Rheingold, A. L. *Organometallics* **1993**, *12*, 1976.

(5) (a) Nutt, W. R.; Blanton, J. S.; Boccanfuso, A. M.; Silks, L. A.; Garber, A. R.; Odom, J. D. *Inorg. Chem.* **1991**, *30*, 4136. (b) Nutt, W. R.; Blanton, J. S.; Kroh, F. O.; Odom, J. D. *Inorg. Chem.* **1989**, *28*, 2224. (c) Nutt, W. R.; Anderson, J. A.; Odom, J. D.; Williamson, M. M.; Rubin, B. H. *Inorg. Chem.* **1985**, *24*, 159. (d) Nutt, W. R.; Stimson, R. E.; Leopold, M. F.; Rubin, B. H. *Inorg. Chem.* **1982**, *21*, 1909.

(6) (a) George, T. A.; Lappert, M. F. *Chem. Commun.* **1966**, 463. (b) George, T. A.; Lappert, M. F. *J. Chem. Soc. A* **1969**, 992.

(7) Veith, M.; Lange, H.; Belo, A.; Recktenwald, O. *Chem. Ber.* **1985**, *118*, 1600.

(8) Jones, K.; Lappert, M. F. *J. Chem. Soc.* **1965**, 1944.

(9) Davies, A. G.; Smith, P. J. In *Comprehensive Organometallic Chemistry*; Wilkinson, G., Ed.; Pergamon Press: Oxford, U.K., 1982; Vol. 2, p 608.

(10) Shriver, D. F.; Drezdson, M. A. *The Manipulation of Air-Sensitive Compounds*, 2nd ed.; Wiley-Interscience: New York, 1986.

(11) Dilts, J. A.; Shriver, D. F. *J. Am. Chem. Soc.* **1968**, *90*, 5769.

Table 1. Experimental Data from the X-ray Diffraction Study

	[Et ₂ GaN(<i>i</i> -Bu) ₂] ₂	[Me ₂ Ga(<i>i</i> -Pr)SnMe ₃] ₂	[Me ₂ GaN(C ₆ H ₁₁) ₂] ₂	[Et ₂ GaN(C ₆ H ₁₁) ₂] ₂
cryst syst	monoclinic	monoclinic	monoclinic	triclinic
space group	<i>P</i> 2 ₁ / <i>n</i> (No. 14)	<i>P</i> 2 ₁ / <i>n</i> (No. 14)	<i>P</i> 2 ₁ / <i>c</i> (No. 14)	<i>P</i> 1̄ (No. 2)
cell dimens ^a				
<i>a</i> , Å	10.252(4)	8.770(2)	11.560(6)	19.024(6)
<i>b</i> , Å	24.129(8)	15.124(3)	9.537(2)	19.325(8)
<i>c</i> , Å	12.086(5)	9.622(1)	13.509(7)	10.158(2)
α, deg				100.17(3)
β, deg	101.75(3)	94.82(1)	107.14(4)	102.25(2)
γ, deg				109.83(3)
<i>V</i> , Å ³	2927(21)	1271(2)	1423(19)	3305(61)
<i>Z</i>	4	2	2	4
mol wt	512.2	641.4	560.2	616.3
ρ(calcd), g cm ⁻³	1.16	1.68	1.31	1.24
radiation			Mo Kα (0.71069 Å)	
monochromator			graphite	
2θ range, deg			4–46	
scan type			ω/2θ	
scan speed, deg min ⁻¹			1–3 (in ω)	
scan width, deg			0.8 + 0.35 tan θ	
no. of unique data	4406	1768	2158	9179
no. of unique data with <i>F</i> ₀ ² > 3σ(<i>F</i> ₀ ²)	3716		1840	
<i>R</i> ^b	0.0655	0.0326 ^d	0.0613	0.0824 ^d
<i>R</i> _w ^c	0.0574	0.0799 ^e	0.0685	0.1495 ^e

^a Unit cell parameters were derived from a least-squares refinement of 25 reflections: 11.63° ≤ θ ≤ 13.78°, 9.31° ≤ θ ≤ 12.31°, 10.01° ≤ θ ≤ 13.99°, 9.47° ≤ θ ≤ 12.05°. ^b *R* = Σ||*F*₀| - |*F*_c||/Σ|*F*₀|. ^c *R*_w = [Σ||*F*₀| - |*F*_c||w^{1/2}/Σ|*F*₀|w^{1/2}]. ^d *R*1 for all reflection data in SHELXL-93. ^e w*R*2 = [Σw(*F*₀² - *F*_c²)/Σw(*F*₀²)]^{1/2} for all reflection data in SHELXL-93.

converted to a waxy, white solid over a period of 1.2 h. The ampule was allowed to stand at room temperature for 20.3 h, and a powdery, white solid along with a liquid formed. Recrystallization of the solid from pentane gave [Me₂GaN(C₆H₁₁)₂]₂ (0.617 g, 81.0% yield): mp 190–191 °C; ¹H NMR (500.138 MHz) δ 3.08 (triplet of triplets, ³*J*_{ax-ax} = 11.6 Hz, ³*J*_{ax-eq} = 2.1 Hz, NCHCH₂CH₂CH₂CH₂CH₂, 2.0H), 1.95 (d, ²*J*_{ax-eq} ≈ 12.1 Hz, NCHC(*H*_{eq})HCH₂CH₂CH₂CH₂C(*H*_{eq})H, 4.2H), 1.74 (d, ²*J*_{ax-eq} ≈ 12.8 Hz, NCHCH₂C(*H*_{eq})HCH₂C(*H*_{eq})HCH₂, 4.2H), 1.57 (d, ²*J*_{ax-eq} ≈ 13.0 Hz, NCHCH₂CH₂C(*H*_{eq})HCH₂CH₂, 2.3H), 1.47 (quartet of doublets, ²*J*_{ax-eq} ≈ ³*J*_{ax-ax} ≈ 12.0 Hz, ³*J*_{ax-eq} = 2.7 Hz, NCHC(*H*_{ax})HCH₂CH₂CH₂C(*H*_{ax})H, 3.7H), 1.25 (quartet of triplets, ²*J*_{ax-eq} ≈ ³*J*_{ax-ax} ≈ 12.8 Hz, ³*J*_{ax-eq} = 3.1 Hz, NCHCH₂C(*H*_{ax})HCH₂C(*H*_{ax})HCH₂, 4.0H), 1.04 (quartet of triplets, ²*J*_{ax-eq} ≈ ³*J*_{ax-ax} ≈ 13.0 Hz, ³*J*_{ax-eq} = 4.1 Hz, NCHCH₂CH₂C(*H*_{ax})HCH₂CH₂, 1.9H), 0.01 (s, (CH₃)₂Ga, 6.1H); ¹³C NMR (75.469 MHz) δ 64.9 (NCHCH₂CH₂CH₂CH₂CH₂), 38.3 (NCHCH₂CH₂CH₂CH₂CH₂), 28.5 (NCHCH₂CH₂CH₂CH₂CH₂), 26.7 (NCHCH₂CH₂CH₂CH₂CH₂), -1.9 ((CH₃)₂Ga). Anal. Calcd for C₂₈H₅₆Ga₂N₂: C, 60.03; H, 10.08; N, 5.00. Found: C, 60.13; H, 10.19; N, 5.06. Molecular weight for C₂₈H₅₆Ga₂N₂: calcd, 560; found, 5.5 × 10² (calculated molality 0.0267).

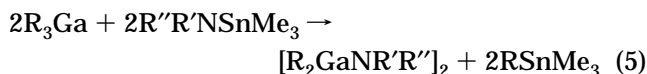
[Et₂GaN(C₆H₁₁)₂]₂. A solution of Et₃Ga (1.51 g, 9.64 mmol) and (C₆H₁₁)₂NSnMe₃ (3.24 g, 9.40 mmol) was heated at 52–53 °C for 10.9 days. Clear, colorless crystals slowly precipitated during this period. The crystalline [Et₂GaN(C₆H₁₁)₂]₂ (2.33 g, 80.4% yield) was washed four times with pentane: mp 142–143 °C; ¹H NMR (500.138 MHz) δ 3.03 (triplet of triplets, ³*J*_{ax-ax} = 11.7 Hz, ³*J*_{ax-eq} = 2.1 Hz, NCHCH₂CH₂CH₂CH₂CH₂, 2.0H), 1.94 (d, ²*J*_{ax-eq} ≈ 12.1 Hz, NCHC(*H*_{eq})HCH₂CH₂CH₂C(*H*_{eq})H, 4.2H), 1.76 (d, ²*J*_{ax-eq} ≈ 12.8 Hz, NCHCH₂C(*H*_{eq})HCH₂C(*H*_{eq})HCH₂, 4.2H), 1.57 (d, ²*J*_{ax-eq} ≈ 12.9 Hz, NCHCH₂CH₂C(*H*_{eq})HCH₂CH₂, 2.3H), 1.52 (quartet of doublets, ²*J*_{ax-eq} ≈ ³*J*_{ax-ax} ≈ 12.0 Hz, ³*J*_{ax-eq} = 2.7 Hz, NCHC(*H*_{ax})HCH₂CH₂CH₂C(*H*_{ax})H, 4.0H), 1.37 (t, ³*J*_{H-H} = 8.0 Hz, (CH₃CH₂)₂Ga, 6.2H), 1.26 (quartet of triplets, ²*J*_{ax-eq} ≈ ³*J*_{ax-ax} ≈ 12.9 Hz, ³*J*_{ax-eq} = 3.0 Hz, NCHCH₂C(*H*_{ax})HCH₂C(*H*_{ax})HCH₂, 4.2H), 1.04 (quartet of triplets, ²*J*_{ax-eq} ≈ ³*J*_{ax-ax} ≈ 13.0 Hz, ³*J*_{ax-eq} = 4.0 Hz, NCHCH₂CH₂C(*H*_{ax})HCH₂CH₂, 2.0H), 0.72 (q, ³*J*_{H-H} = 8.0 Hz, (CH₃CH₂)₂Ga, 4.0H); ¹³C NMR (75.469 MHz) δ 64.4 (NCHCH₂CH₂CH₂CH₂CH₂), 38.2 (NCHCH₂CH₂CH₂CH₂CH₂), 28.5 (NCHCH₂CH₂CH₂CH₂CH₂), 26.6 (NCHCH₂CH₂CH₂CH₂CH₂), 11.1 ((CH₃CH₂)₂Ga), 7.2 ((CH₃CH₂)₂Ga). Anal. Calcd for C₃₂H₆₄Ga₂N₂: C, 62.36; H, 10.47; N, 4.54. Found: C, 62.48;

H, 10.74; N, 4.67. Molecular weight for C₃₂H₆₄Ga₂N₂: calcd, 616; found, 5.9 × 10² (calculated molality 0.0277).

X-ray Crystallographic Analysis. Colorless crystals of [Et₂GaN(*i*-Bu)₂]₂, [Me₂GaN(*i*-Pr)SnMe₃]₂, [Me₂GaN(C₆H₁₁)₂]₂, and [Et₂GaN(C₆H₁₁)₂]₂ were mounted in capillary tubes under a nitrogen atmosphere. The determination of the unit cell and the collection of the intensity data were made on a CAD-4 diffractometer equipped with a graphite monochromator. Unit cell parameters and details of the data collection are given in Table 1. The positions of the C, N, Ga, and Sn atoms were taken from Patterson maps. After several cycles of a full-matrix least-squares refinement with all non-hydrogen atoms anisotropic, the hydrogen atoms were generated at calculated positions (C–H = 0.96 Å; H–C–H = 109.5°) with rigid geometry. Additional cycles of refinement led to convergence. All calculations were performed on a DEC VAX 8530 or IBM PS/2 Model 90 computer using ORFFE4,¹² SHELXS-86,^{13a} and SHELX-76^{13b} or SHELXL-93.^{13c} Scattering factors for all atoms included real and imaginary anomalous dispersion components.¹⁴ Selected bond lengths and angles are given in Tables 2–5.

Results and Discussion

The alkyltrimethyltin elimination reaction (eq 5) of R₃Ga (R = Me, Et) with R'R'NSnMe₃ (R' = *i*-Bu, SnMe₃, C₆H₁₁ and R' = *i*-Bu, *i*-Pr, C₆H₁₁) in the absence of a solvent gave [Me₂GaN(*i*-Bu)₂]₂, [Et₂GaN(*i*-Bu)₂]₂, [Me₂GaN(*i*-Pr)SnMe₃]₂, [Me₂GaN(C₆H₁₁)₂]₂, and [Et₂GaN(C₆H₁₁)₂]₂ in 88.6, 68.6, 69.1, 81.0, and 80.4% yields.



In all cases except one, the neat reactants were heated

(12) Busing, W. R.; Martin, K. O.; Levy, H. A. ORFFE (revised by F. M. Brown, C. K. Johnson, and W. E. Thiessen); Oak Ridge National Laboratory: Oak Ridge, TN, 1985.

(13) (a) Sheldrick, G. M. *Acta Crystallogr.* **1990**, *A46*, 467. (b) Sheldrick, G. M. *SHELX-76 Program for Crystal Structure Determination*; Cambridge University Press: New York, 1975. (c) Sheldrick, G. M. SHELXL-93; University of Göttingen, Göttingen, Germany, 1993.

(14) Cromer, D. T.; Waber, J. T. *International Tables for X-Ray Crystallography*; Kynoch Press: Birmingham, England, 1974; Vol. IV.

Table 2. Selected Intramolecular Distances (Å) and Bond Angles (deg) for [Et₂GaN(*i*-Bu)₂]₂

Distances			
Ga(1)···Ga(2)	2.864(1)	N(1)···N(2)	2.837(9)
Ga(1)–N(1)	2.061(6)	Ga(1)–N(2)	2.068(6)
Ga(2)–N(1)	2.053(6)	Ga(2)–N(2)	2.035(6)
Ga(1)–C(1)	2.010(8)	Ga(1)–C(3)	1.983(9)
Ga(2)–C(5)	1.975(8)	Ga(2)–C(7)	1.993(9)
N(1)–C(9)	1.484(10)	N(1)–C(13)	1.495(10)
N(2)–C(17)	1.494(10)	N(2)–C(21)	1.489(10)
Angles			
N(1)–Ga(1)–N(2)	86.8(2)	N(1)–Ga(2)–N(2)	87.9(2)
C(1)–Ga(1)–C(3)	123.2(4)	C(5)–Ga(2)–C(7)	112.7(4)
C(1)–Ga(1)–N(1)	110.2(3)	C(7)–Ga(2)–N(1)	107.4(3)
C(1)–Ga(1)–N(2)	109.4(3)	C(7)–Ga(2)–N(2)	109.4(3)
C(3)–Ga(1)–N(1)	111.2(4)	C(5)–Ga(2)–N(1)	120.4(4)
C(3)–Ga(1)–N(2)	110.0(4)	C(5)–Ga(2)–N(2)	116.3(3)
Ga(1)–N(1)–Ga(2)	88.2(2)	Ga(1)–N(2)–Ga(2)	88.5(2)
C(9)–N(1)–C(13)	112.1(7)	C(17)–N(2)–C(21)	111.5(7)
C(9)–N(1)–Ga(1)	118.5(5)	C(17)–N(2)–Ga(1)	118.3(4)
C(9)–N(1)–Ga(2)	110.3(5)	C(17)–N(2)–Ga(2)	109.8(5)
C(13)–N(1)–Ga(1)	111.1(5)	C(21)–N(2)–Ga(1)	110.3(5)
C(13)–N(1)–Ga(2)	114.7(5)	C(21)–N(2)–Ga(2)	116.9(5)

Table 3. Selected Intramolecular Distances (Å) and Bond Angles (deg) for [Me₂GaN(*i*-Pr)SnMe₃]₂

Distances			
Ga···Ga'	2.892(1)	N···N'	2.859(7)
Ga–N	2.039(4)	Ga–N'	2.028(4)
Ga–C(1)	1.984(5)	Ga–C(2)	1.975(5)
N–C(3)	1.513(6)	N–Sn	2.112(4)
Sn–C(6)	2.135(6)	Sn–C(7)	2.143(7)
Sn–C(8)	2.148(6)		
Angles			
N–Ga–N'	89.3(2)	Ga–N–Ga'	90.7(2)
C(1)–Ga–C(2)	110.0(3)	C(1)–Ga···Ga'	125.6(2)
C(2)–Ga···Ga'	124.4(2)	C(1)–Ga–N	113.4(2)
C(2)–Ga–N	114.4(2)	C(1)–Ga–N'	115.6(2)
C(2)–Ga–N'	113.0(2)	C(3)–N–Sn	114.0(3)
C(3)–N···N'	122.4(3)	Sn–N···N'	123.6(2)
C(3)–N–Ga	111.9(3)	C(3)–N–Ga'	112.4(3)
Sn–N–Ga	112.6(2)	Sn–N–Ga'	113.2(2)

Table 4. Selected Intramolecular Distances (Å) and Bond Angles (deg) for [Me₂GaN(C₆H₁₁)₂]₂

Distances			
Ga···Ga'	2.911 (2)	N···N'	2.938 (9)
Ga–N	2.070 (5)	Ga–N'	2.066 (4)
Ga–C(1)	1.981 (9)	Ga–C(2)	1.978 (8)
N–C(3)	1.499 (7)	N–C(9)	1.498 (9)
Angles			
N–Ga–N'	90.5 (2)	Ga–N–Ga'	89.5 (2)
C(1)–Ga–C(2)	116.1 (5)	C(1)–Ga···Ga'	121.9 (4)
C(2)–Ga···Ga'	122.0 (3)	C(1)–Ga–N	111.7 (4)
C(2)–Ga–N	112.2 (3)	C(1)–Ga–N'	111.9 (3)
C(2)–Ga–N'	111.7 (3)	C(3)–N–C(9)	118.3 (5)
C(3)–N···N'	121.0 (4)	C(9)–N···N'	120.7 (4)
C(3)–N–Ga	112.3 (3)	C(3)–N–Ga'	110.7 (4)
C(9)–N–Ga	110.3 (4)	C(9)–N–Ga'	112.2 (3)

at temperatures between 44 and 57 °C for periods of 6 h to 10.9 days. The exception is the reaction of Me₃Ga with (C₆H₁₁)₂NSnMe₃, in which the reaction mixture was allowed to stand at room temperature for 20.3 h. All five aminogallanes are colorless crystalline solids at room temperature.

The X-ray crystallographic study of [Et₂GaN(*i*-Bu)₂]₂, [Me₂GaN(*i*-Pr)SnMe₃]₂, [Me₂GaN(C₆H₁₁)₂]₂, and [Et₂GaN(C₆H₁₁)₂]₂ reveals that the four aminogallanes are dimeric in the solid state (Figures 1–4). The narrow melting point range for [Me₂GaN(*i*-Pr)SnMe₃]₂ indicates that only one isomer is present in the solid state, and it is the *trans* isomer (Figure 2). The four-membered (Ga–N)₂ rings in [Et₂GaN(*i*-Bu)₂]₂ and [Et₂GaN(C₆H₁₁)₂]₂

(molecules 1 and 2) are nonplanar with fold angles on the Ga···Ga diagonals of 148.7(3) and 146.3(3), 147.7(3)°. These angles are smaller than the fold angles of 154.2 and 171.8(2)° that were observed in the only other reported aminogallanes [Me₂GaN(H)Dipp]₂ (Dipp = 2,6-*i*-Pr₂C₆H₃)^{2a} and [(2,3-Me₂C₄H₄)GaNEt₂]₂^{3g} with nonplanar (Ga–N)₂ rings. The Ga-methylated aminogallanes and all other substituted dimeric aminogallanes^{2a,i,3–f} for which structural data are known contain planar (Ga–N)₂ rings. Steric overcrowding between substituents on neighboring atoms in the (Ga–N)₂ ring and packing forces are probably responsible for the distortion of the (Ga–N)₂ rings in the Ga-ethylated aminogallanes.

The C–Ga bond lengths (Tables 4 and 5) in [Et₂GaN(C₆H₁₁)₂]₂ (average 1.996(7), 1.996(7) Å) are slightly longer than the corresponding bond lengths in [Me₂GaN(C₆H₁₁)₂]₂ (average 1.980(9) Å). The longer C–Ga bonds in the former aminogallane probably result from an increase in substitution on the carbon atoms bonded to the gallium atoms. A similar trend is found in the C–Ga bond distances for [(*i*-Bu)₂GaN(H)Ph]₂ (2.006(9) and 2.18(2) Å)^{3e} and [Me₂GaN(H)Ph]₂ (1.954(6) and 1.936(6) Å).^{2a} Despite significant variations in the N–Ga bond lengths in molecule 1 of [Et₂GaN(C₆H₁₁)₂]₂, the average N–Ga bond distances in molecules 1 and 2 (2.070(5), and 2.069(5) Å) are nearly identical with the average N–Ga bond length (2.068(5) Å) found in [Me₂GaN(C₆H₁₁)₂]₂. By comparison, the average N–Ga distances in [Et₂GaN(*i*-Bu)₂]₂ (2.054(6) Å) and *trans*-[Me₂GaN(*i*-Pr)SnMe₃]₂ (2.034(4) Å) are shorter. The small decrease in the average N–Ga bond length within the series [R₂GaN(C₆H₁₁)₂]₂, [Et₂GaN(*i*-Bu)₂]₂, and *trans*-[Me₂GaN(*i*-Pr)SnMe₃]₂ can be attributed to the decrease in the steric requirements of nitrogen substituents in the series.

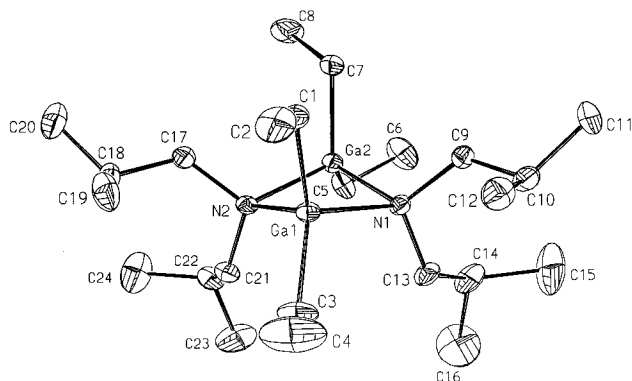
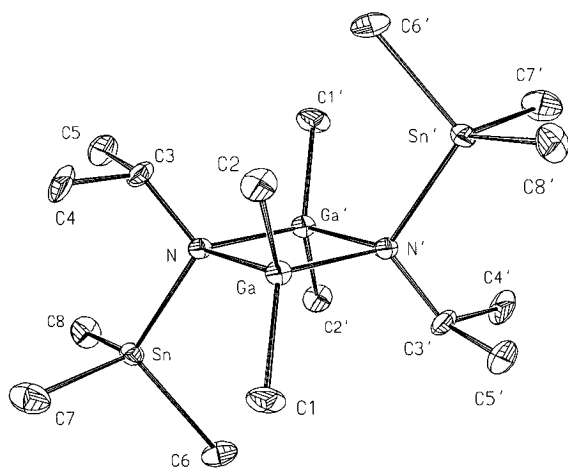
Cryoscopic molecular weight measurements indicate that all five aminogallanes are dimers in benzene solutions. *trans*-[Me₂GaN(*i*-Pr)SnMe₃]₂ appears to be the only isomer present in a toluene solution at room temperature. The ¹H NMR spectrum of [Me₂GaN(*i*-Pr)SnMe₃]₂ in toluene exhibited only one Ga–CH₃ resonance. Two additional Ga–CH₃ resonances of equal intensity would be expected if the *cis* isomer were also present in the solution.^{2d,4}

The nonplanar (Ga–N)₂ rings in [Et₂GaN(*i*-Bu)₂]₂ and [Et₂GaN(C₆H₁₁)₂]₂ render the two ethyl groups on a gallium atom and the two substituents on a nitrogen atom magnetically nonequivalent in the solid state. However, the ¹H NMR spectrum of each Ga-ethylated aminogallane in toluene solution exhibited only one signal for the methyl protons and one signal for the methylene protons in the ethyl group at room temperature. At –68 °C the width of the bands at half-height increased to 5 Hz—probably due to the increase in viscosity of the toluene solution—but only one quartet and one triplet were observed for the methyl and methylene protons in the spectra of [Et₂GaN(*i*-Bu)₂]₂ and [Et₂GaN(C₆H₁₁)₂]₂. Either the rate of inversion of the (Ga–N)₂ rings in both aminogallanes is very fast in comparison to the NMR time scale or the rings are planar in solution.

The signals associated with the axial and equatorial protons on the cyclohexyl groups are well-resolved in the ¹H NMR spectra of [Me₂GaN(C₆H₁₁)₂]₂ and [Et₂GaN-

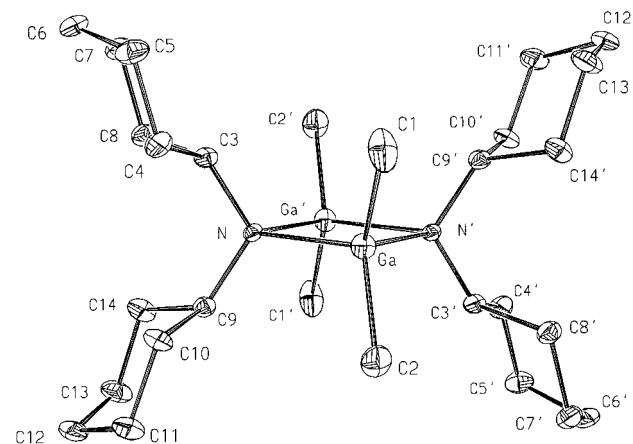
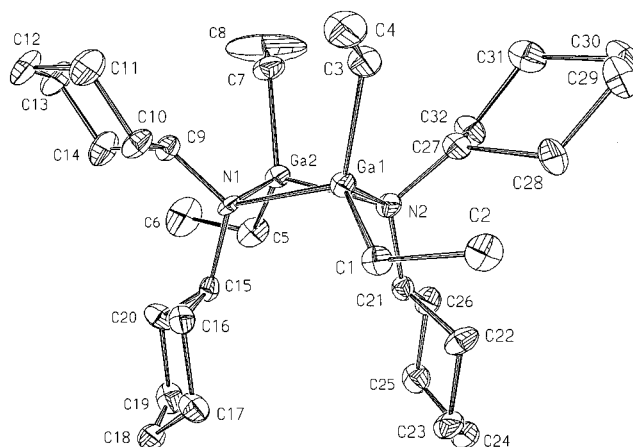
Table 5. Selected Intramolecular Distances (Å) and Bond Angles (deg) for $[\text{Et}_2\text{GaN}(\text{C}_6\text{H}_{11})_2]_2$ ^a

Distances			
Ga(1)···Ga(2)	2.878(1), 2.872(1)	N(1)···N(2)	2.849(8), 2.862(9)
Ga(1)–N(1)	2.049(5), 2.069(5)	Ga(1)–N(2)	2.086(5), 2.064(5)
Ga(2)–N(1)	2.086(5), 2.072(5)	Ga(2)–N(2)	2.061(5), 2.072(5)
Ga(1)–C(1)	1.990(6), 1.992(7)	Ga(1)–C(3)	1.999(7), 2.002(7)
Ga(2)–C(5)	2.004(7), 1.994(8)	Ga(2)–C(7)	1.993(7), 1.996(7)
N(1)–C(9)	1.496(8), 1.531(8)	N(1)–C(15)	1.519(8), 1.491(8)
N(2)–C(21)	1.521(8), 1.518(8)	N(2)–C(27)	1.483(8), 1.534(8)
Angles			
N(1)–Ga(1)–N(2)	87.1(2), 87.7(2)	N(1)–Ga(2)–N(2)	86.8(2), 87.4(2)
Ga(1)–N(1)–Ga(2)	88.2(2), 87.8(2)	Ga(1)–N(2)–Ga(2)	87.9(2), 88.0(2)
C(1)–Ga(1)–C(3)	110.4(3), 113.2(3)	C(5)–Ga(2)–C(7)	113.1(3), 112.6(4)
C(1)–Ga(1)–N(1)	114.6(2), 113.7(3)	C(5)–Ga(2)–N(1)	120.3(3), 118.2(3)
C(3)–Ga(1)–N(1)	112.9(3), 111.7(3)	C(7)–Ga(2)–N(1)	109.4(3), 108.9(3)
C(1)–Ga(1)–N(2)	121.1(3), 117.7(3)	C(5)–Ga(2)–N(2)	112.9(3), 115.6(3)
C(3)–Ga(1)–N(2)	108.9(3), 119.2(3)	C(7)–Ga(2)–N(2)	111.6(3), 111.7(3)
C(9)–N(1)–C(15)	117.7(5), 118.0(5)	C(21)–N(2)–C(27)	118.5(5), 116.5(5)
C(9)–N(1)–Ga(1)	113.4(4), 110.7(4)	C(21)–N(2)–Ga(1)	115.8(4), 116.6(4)
C(15)–N(1)–Ga(1)	108.9(4), 112.2(4)	C(27)–N(2)–Ga(1)	109.0(4), 109.0(4)
C(9)–N(1)–Ga(2)	109.8(4), 109.7(4)	C(21)–N(2)–Ga(2)	107.8(4), 112.4(4)
C(15)–N(1)–Ga(2)	115.1(4), 114.5(4)	C(27)–N(2)–Ga(2)	113.8(4), 111.0(4)

^a Data are given the order molecule 1, molecule 2.**Figure 1.** ORTEP diagram of $[\text{Et}_2\text{GaN}(i\text{-Bu})_2]_2$.**Figure 2.** ORTEP diagram of $[\text{Me}_2\text{Ga}(i\text{-Pr})\text{SnMe}_3]_2$.

$(\text{C}_6\text{H}_{11})_2]_2$. The three doublets in the region from 2.0 to 1.57 ppm were assigned to the equatorial protons on the β -, γ -, and δ -carbon atoms, and the three quartets of doublets or triplets in the region from 1.52 to 1.0 ppm were assigned to the axial protons on the β -, γ -, and δ -carbon atoms. These assignments are consistent with the COSY contour plots of the aminogallanes and spectral features distinctive to cyclohexyl groups.¹⁵

(15) Morelle, N.; Gharbi-Benarous, J.; Acher, F.; Valle, G.; Crisma, M.; Toniolo, C.; Azerad, R.; Girault, J. *J. Chem. Soc., Perkin Trans. 2* **1993**, 525.

**Figure 3.** ORTEP diagram of $[\text{Me}_2\text{GaN}(\text{C}_6\text{H}_{11})_2]_2$.**Figure 4.** ORTEP diagram of $[\text{Et}_2\text{GaN}(\text{C}_6\text{H}_{11})_2]_2$ (molecule 1).

The alkyltrimethyltin elimination reaction (eq 5) affords a convenient, single-step, low-temperature pathway to substituted Ga-methylated or Ga-ethylated aminogallanes. With the exception of the reaction of Et_3Ga with $(\text{C}_6\text{H}_{11})_2\text{NSnMe}_3$, which required 10.9 days, the elimination reactions that were investigated proceeded readily in the absence of a solvent at or below 57 °C. Even when the substituents on the nitrogen atom were the bulky cyclohexyl groups, the aminogallanes $[\text{Me}_2\text{GaN}(\text{C}_6\text{H}_{11})_2]_2$ and $[\text{Et}_2\text{GaN}(\text{C}_6\text{H}_{11})_2]_2$ were obtained in

good yields. Attempts to prepare $[\text{Me}_2\text{GaN}(\text{C}_6\text{H}_{11})_2]_2$ by cyclopentadiene elimination (eq 4) were unsuccessful,⁴ and the adduct $\text{Me}_3\text{Ga}\cdot\text{N}(\text{H})(\text{C}_6\text{H}_{11})_2$ has been found to be stable to methane elimination (eq 1) during sublimation at 40–60 °C and 0.01 Torr.^{3c} It should be noted that, at least in the case of the reactions of Me_3Ga or Et_3Ga with $(\text{C}_6\text{H}_{11})_2\text{NSnMe}_3$, higher reaction temperatures and longer reaction times were required to effect the formation of $[\text{Et}_2\text{GaN}(\text{C}_6\text{H}_{11})_2]_2$ than $[\text{Me}_2\text{GaN}(\text{C}_6\text{H}_{11})_2]_2$.

Acknowledgment. The support of this research by the Research Corp. and the donors of the Petroleum

Research Fund, administered by the American Chemical Society, is gratefully acknowledged. J.M.G., J.D.O., Y.D., and L.L. gratefully acknowledge financial support from the NSF/EPSCoR (Grant ESR-9108772).

Supporting Information Available: Listings of bond lengths, bond angles, selected dihedral angles, hydrogen coordinates, anisotropic temperature factors, and final positional parameters for $[\text{Et}_2\text{GaN}(i\text{-Bu})_2]_2$, $[\text{Me}_2\text{GaN}(i\text{-Pr})\text{SnMe}_3]_2$, $[\text{Me}_2\text{GaN}(\text{C}_6\text{H}_{11})_2]_2$, and $[\text{Et}_2\text{GaN}(\text{C}_6\text{H}_{11})_2]_2$ and COSY plots for $[\text{Me}_2\text{GaN}(\text{C}_6\text{H}_{11})_2]_2$ and $[\text{Et}_2\text{GaN}(\text{C}_6\text{H}_{11})_2]_2$ (40 pages). Ordering information is given on any current masthead page.

OM950812H